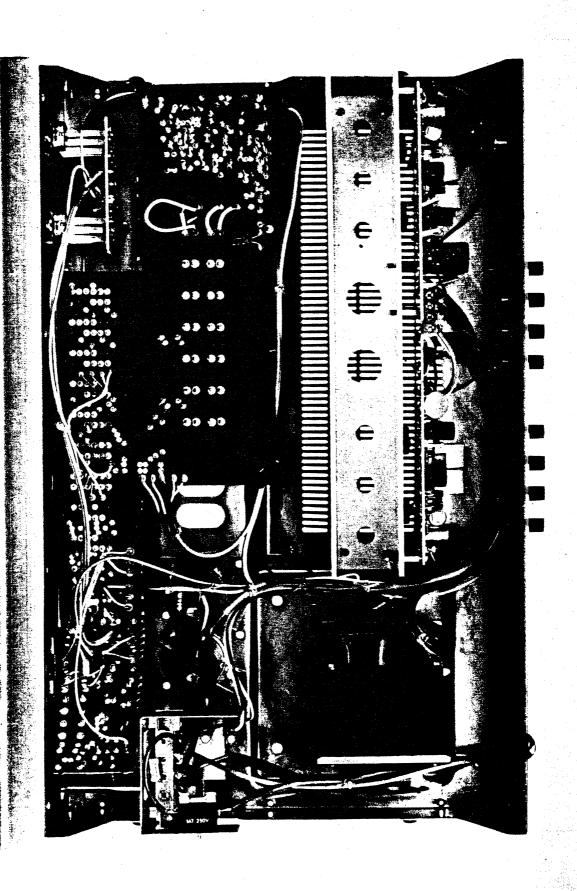
# SERVICE MANUAL

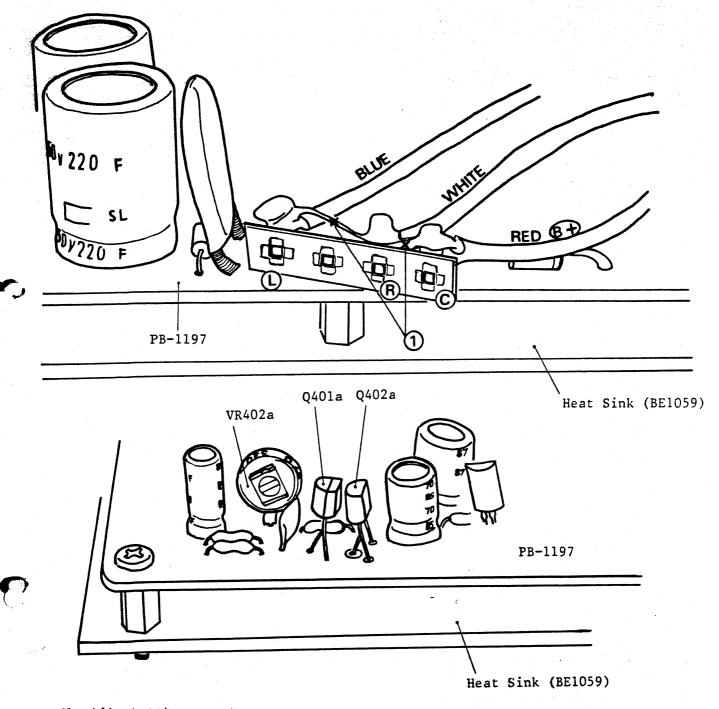
## SOLID STATE STEREO L-2





一种 不是我的人

0

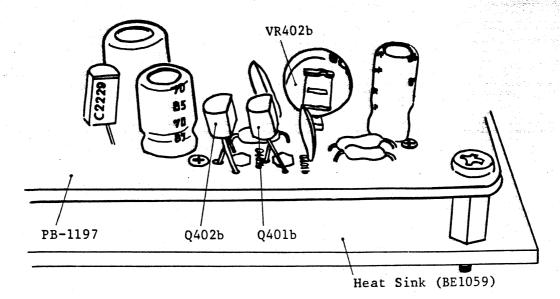


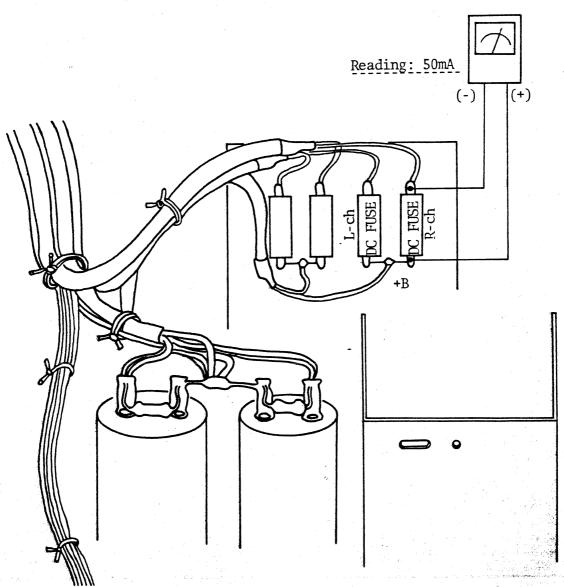
#### Idle Adjustment

- (1) Cut the jumper lead, as described in the illustration.
- (2) Connect a resistor 10 ohms 1W across (L) and (C).

  Connect a DC amperemeter (full scale 250 300mA) between

  (R) and (C). (polarization: (C) + ) Adjust VR402b to
  obtain 50mA reading on the meter. (R-ch idle adjust)
- (3) Disconnect the lead of the resistor connected to (L), and connect it to (R), leaving the lead connected to (C) as it is. Connect a DC amperemeter between (L) and (C). (polarization: (C) + ) Adjust VR402a to obtain 50mA reading on the meter. (L-ch idle adjust)
- (4) Connect (C) (R), and (R) (L) again by use of jumper
- (5) This adjustment should be done 1 minute after turning the power on.

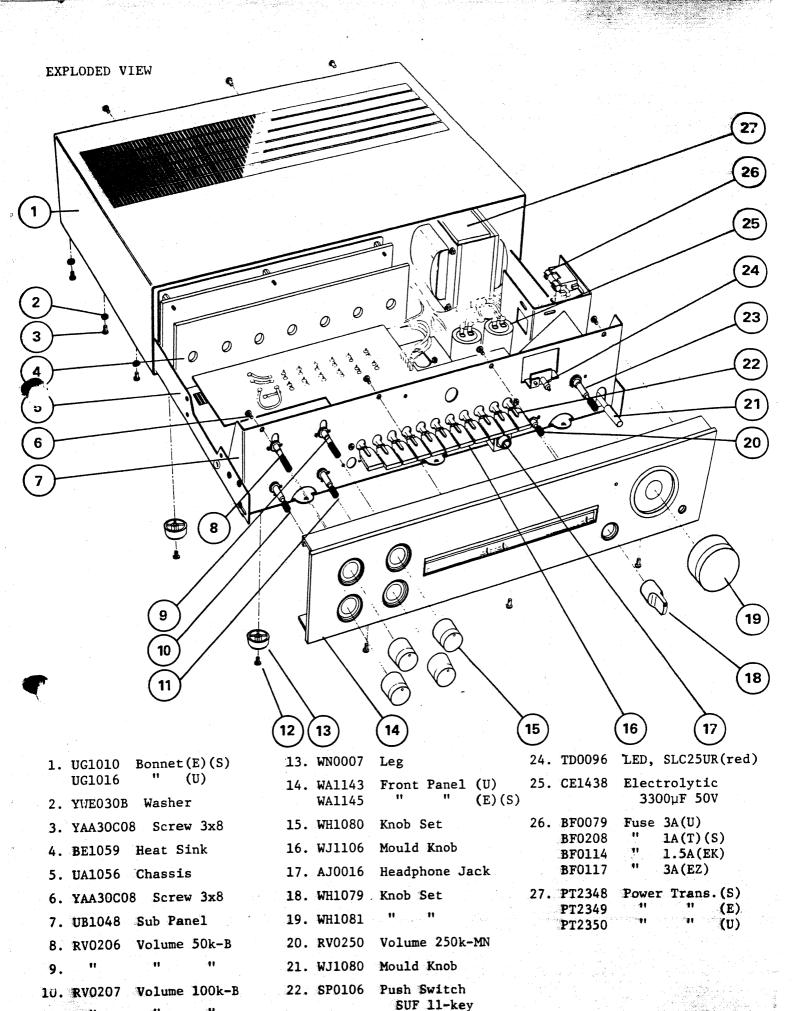




Idle current can be measured by removing the two DC Fuses for L-ch and R-ch. Connect an amperemeter (full scale 250-300mA) across the fuse holder as depicted.

Note that in the case of measuring that for the L-ch, be sure to insert the R-ch fuse in the holder, and vice versa for the R-ch.

Adjust VR402a(R-ch) or VR402b(L-ch) to obtain 50mA reading on the amperemeter.



23. RV0204 Volume 200k-B x 2

11.

12. YJB40A08 Tapping Screw

#### REMARKS

Capacitors: C....ceramic, E....electrolytic, M....mylar, G.....G capacitor

S....styrol, T....tantalum, Mi...mica, MP....MP capacitor O....oil capacitor, TRIM....trimmer capacitor, AC....AC capacitor

BP....electrolytic Bi-Polar type

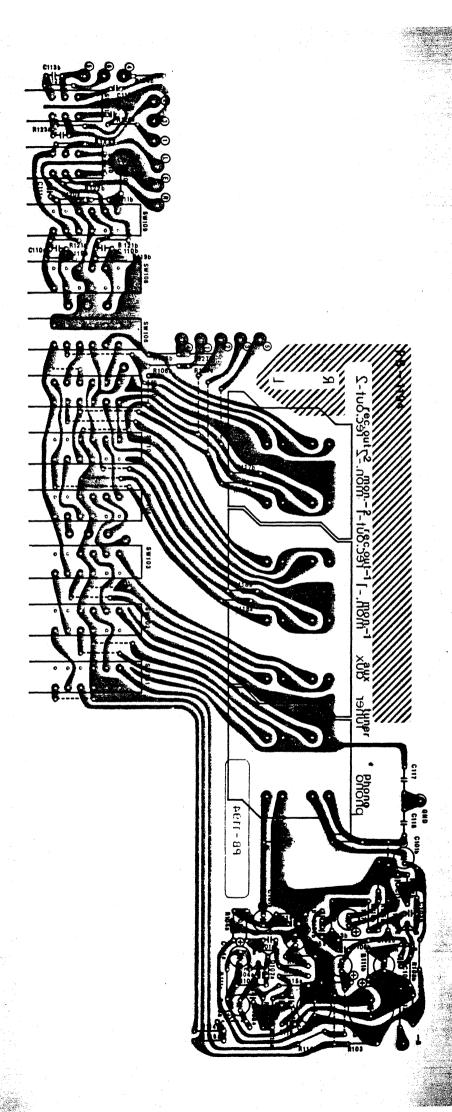
Resistors: ±5%, 1/4W, unless specified otherwise

Type: (S).... model for north European countries (U).... model for U.S.A. and CANADA

(J).... model for JAPAN

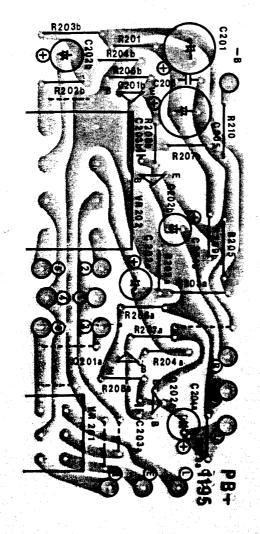
#### PB1194

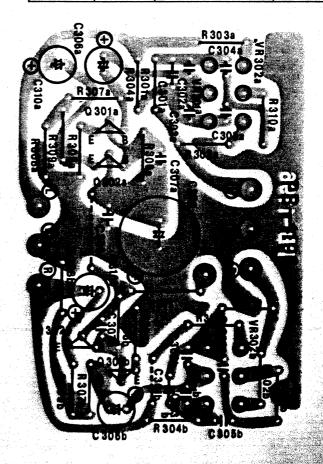
_				
[	NO.	STOCK NO.	DESCRIPTION	LOCA- TION
T,	R101ab	RB0224	56K	
- 1	102ab	246	470K	
١	10225	210	15K	
	103 104ab	254	1M	
-	104ab 105ab	182	1K	
	105ab	234	150K	
-	Todab	234	(E)(S)	
-	107ab	174	470	
	107ab	230	100K	
-	100ab 109ab	222	47K	
1	109ab	180	820	
-	lllab	184	1.2K	
	111ab	220	39K	1
	112ab 113ab	252	820K	
-	113ab	174	470	
	114ab 115ab	204	8.2K	
1	115ab	242	330K	
1	110ab	254	1M	
١	117ab 118ab	254	1M	
	110ab 119ab	254	1M	
	119ab 120ab	254	1M	
	120ab	202	6.8K	
	121ab	202	11	
	122ab	208	12K	
	123ab	216	27K	
	1244	RS1078	680 1/4 F	
	125	RB0220	39K	
	127ab	234	150K	
	12/40	234	(E)(S)	
			(2)(0)	
	Q101ab	TR0125	2SA836 E	
	102ab	TR0025	2SC1345 E	
	10280	IROUZS		
	C101ab	CE0173	3.3u 25V E	
	102	CE0079	220µ 16V E	
	103ab	CC0008	150P 50V C	
	104ab	CC0003	4.7P 50V C	1
	105ab	CE0074	10µ 16V E	
	106ab	CQ0130	1000P 50V M	3.2
	107ab	CQ0130	1000P 50V M	
	108ab	CQ0122	6800P 50V M	
	10000	1-,		



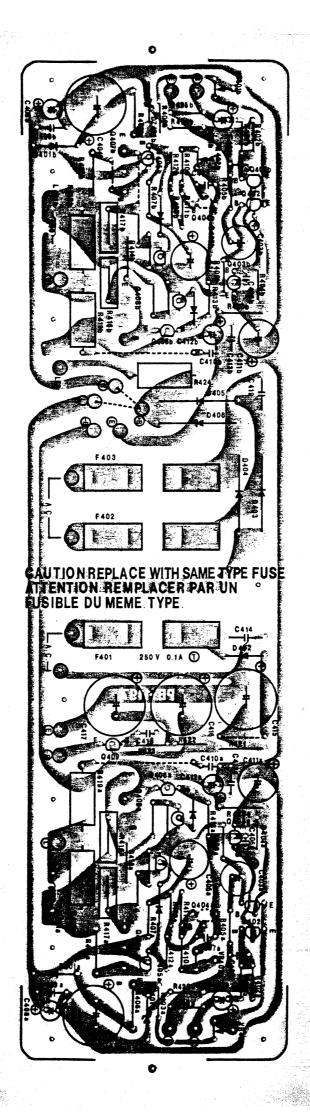
LOCA- TION

SYMBOL NO.	STOCK NO.	DESCRIPTION	LOCA- TION
R301ab	RB0212	18K	
302ab	186	1.5K	
303ab	186	1.5K	jar. se
304ab	212	18K	
<b>3</b> 05ab	190	2.2K	
306ab	220	39K	
<b>3</b> 07ab	244	390K	
308ab	182	1K	
309ab	200	5.6K	
310ab	188	1.8K	
311	RS1094	3.3K F 1/4	
C301ab	CQ0124	0.022μ 50V M	
302ab	CQ0130	1000P 50V M	
303ab	CQ0130	1000P 50V M	
304ab	CQ0334	1800P 50V M	
305ab	CQ0334	1800P 50V M	
306ab	CE0173	3.3µ 25V E	
 307ab	CC0012	10P 25V C	
308	CE0096	220μ 35V E	
309	CK0145	0.022μ 50V C	
310ab	CE0173	3.3μ 25V E	
Q301ab	TR0125	A836 E	
302ab	TR0125	A836 E	
VR301ab	RV0207	100КВ	
5 ·	RV0206	50KB	





SYMBOL NO.	STOCK No.	DESCRIPTION	LOCA- TION	SYMBOL NO.	STOCK No.	DESCRIPTION	LOCA- TION
R40lab	RB0194	3.3K		C414	СК0203	0.01u 500V C	
	RB0206	10K		415	CE0146	220µ 50V E	
	RB0204	8.2K		416	CE0146	220µ 50V E	
	RB0176	560		417	CE0146	220µ 50V E	1200
	RB0176	470		418	CC0007	100P 50V C	a province to the second
	RS2525	1.2K 1/2 F		419	CK0203	0.01µ 500V C	* *
1 1		1.2K 1/2 F	1	419	CRUZUS	0.01P 300V C	
1	RB0188	3.9K		Q401ab	TR0193	A942 RAKK	
1	RB0196	10K		402ab	TR0193	A942 RAKK	
	RB0206	680		1	TR0236	C2229	
1	RB0178			403ab	1	C1740	
411ab	RB0188	1.8K		404ab	TR0146	i	
412ab	RB0150	47		405ab	TR0264	C2235	
413ab	RB0150	47		406ab	TR0263	A965	
414ab	RS0074	100 1/2 F		407ab	TR0262	D716	
415ab	RS0074	100 1/2 F		408ab	TR0261	B686	
416ab	RG0009	0.33		409	TR0125	A836	1
417ab	RG0009	0.33		D401ab	TD0002	1N4002	
418ab	RD0158	10 1W		402ab	TD0003	1N4003	
419ab	RS2709	10 1W F		403	TD0106	S3V40	
420ab	RS0074	100 1/2 F		2	ح	2	
421	RS0074	100 1/2 F		406	11	11	
422	RB0206	10K					
423	RB0182	kK		DZ401	TD0065	WZ192	
424	RS2716	3.3K 1W F		<b>a</b> b			
425ab	RB0242	330K					
426ab	RB0150	47			UC1113 UC1111	Rear Panel (U)	
R001	RD0150	4.7K 1W			UC1112	" (E)	
					UC1124	" (UC)	
L401ab		LUX1004-2 MH			UB1048	Sub Panel	
F401	BF0201	Fuse 0.1A (T)		SW001	SP0063 SP0090	Push SW (U) " (E)(J)(S)	
	BF0074	(S) Fuse 0.5A	· ·		510090	(E)(3)(3)	
	BF0111	(U) Fuse 0.5A		•	AS0002	DIN CONNE.	
		(E)			AH0016	(E)(S) 1P Fuse Holder	
C401ab	CE0173	3.3µ 25V E			4770070	(E)(J)(U)	
402ab	CC0009	220P 50V C			AH0019	1P Fuse Holder	
403ab	CE0077	47μ 16V E		7 11		<b>(</b> S)	
404ab	CE0146	220µ 50V E					
405ab	CE0094	47μ 35V E		F001	BF0079	3A (U)	-
406ab	cc0005	33P 50V C			BF0014	1.5A (EK)	
407ab	CK0157	0.04µ 25V C			BF0117	3A (EZ)(J)	
408ab	CE0098	1μ 50V E			BF0208	1A T (S)	
409ab	CK0146	0.04µ 50V C				1	
410ab	CQ0332	0.039µ 50V M			PT2349	P2349	
411ab	CE0102	47µ 50V E				Power Trans(E)	
412ab	CE0098	14 50V E			PT2348	P2348 (S)	
413ab	CK0146	0.04µ 50V C			PT2350	P2350 (U)	
VR402ab	RT0013	Semifix 330Ω-B		R003 R004	RD0339	470Ω 1W F 470Ω 1W F	
	1 1 1 1 1 1 1	***	100		CE1430		
				C001		3300µF 50V E	



C

#### 2SC1740 (TR3146)

#### Absolute Maximum Ratings (Ta = 25°C)

SYMBOL	RATING	UNIT
V <sub>CBO</sub>	50	V
V <sub>CEO</sub>	40	V
V <sub>EBO</sub>	5	V
<sup>I</sup> c	100	nA.
P <sub>C</sub>	<b>3</b> 00	Water
Tj	125	°C
Tstg	-55 - 125	°C

#### ELECTRICAL CHARACTERISTICS (Ta = 25°C)

SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
BVCEO	Ic=lmA	40	-	-	٧
вусво	I <sub>C</sub> =50uA	50	•	-	٧
BV <sub>EBO</sub>	I <sub>E</sub> =50uA	5	-	-	٧
СВО	V <sub>CB</sub> =30V	-		0.5	μA
I <sub>EBO</sub>	V <sub>EB</sub> =4V	-	-	0.5	μA
V <sub>CE(sat)</sub>	I <sub>C</sub> /I <sub>B</sub> =50mA/5mA	-	-	0.4	v
h <sub>FE</sub>	V <sub>CE</sub> /I <sub>C</sub> =6V/lmA	120	-	560	-
f <sub>T</sub>	V <sub>CE</sub> =12V, I <sub>E</sub> =-2mA	-	180	-	MHz
Сор	V <sub>CB</sub> =12V, I <sub>E</sub> =0, f=1MHz	-	2.0	3.5	pF

### 2SA942RAKK (TR0193)

SYMBOL	RATING	UNIT
v <sub>cbo</sub>	<del>-</del> 90	V
V <sub>CEO</sub>	-90	V
V <sub>EBO</sub>	-5	V
I <sub>C</sub>	<b>-5</b> 0	m.A
I <sub>E</sub>	50	m.A
P <sub>C</sub>	<b>3</b> 00	mW
T <sub>j</sub>	125	°c
T <sub>stg</sub>	-55 - <b>1</b> 25	°C

## Absolute Maximum Ratings (Ta =25°C) ELECTRICAL CHARACTERISTICS (Ta = 25 -15°C)

SYMBOL	CONDITION	MIN.	MAX.	UNIT
I <sub>CBO</sub>	V <sub>CB</sub> =-90V, I <sub>E</sub> =0	-	-0.1	μA
I <sub>EBO</sub>	V <sub>EB</sub> =-5V, I <sub>C</sub> =0	-	-0.1	μA
h <sub>FE</sub>	V <sub>CE</sub> =-6V, I <sub>C</sub> =-2mA	280	700	-
V <sub>CE(sat)</sub>	I <sub>C</sub> =-10mA, I <sub>B</sub> =-1mA	-	-0.4	v
Сор	$V_{CB}$ =-10V, $I_{E}$ =0, f=1MHz	-	5.0	pF
nf	V <sub>CE</sub> =-6V, I <sub>C</sub> =-0.1mA R <sub>2</sub> =10k ohms, f=100Hz	-	6.0	dB

#### 2SB686/2SD716(TR0261/TR0262)

	()	_ //	- (**)					E(sat)		f <sub>T</sub> TYP.
Type No.	A <sup>CEO</sup> (A)	C(A)	P <sub>C</sub> (W)	n <sub>FE</sub>	V <sub>CE</sub> (V)	I <sub>C</sub> (A)	(V)	I <sub>C</sub> (A)	I <sub>B</sub> (A)	(MHz)
25B686 /2SD716	100	6	60	55 - 160	5	1^	2.0	4	0.4	10/12

### 2SA836(TR0125), 2SC1345(TR0025)

Type No.	V <sub>CEO</sub>	I <sub>C</sub> (mA)	P <sub>C</sub> (mW)	h <sub>FE</sub>	f <sub>T</sub> (MHz)	Conditi V <sub>CE</sub> (V)	on I <sub>C</sub> (mA)	NF (dB)	Conditi V <sub>CE</sub> (V)		f (Hz)
2SA836	-55	-100	200	160 to <b>8</b> 00	200	-12	-2	1	-6	-0.1	1k
2SC1345	· 50	100	200	250 to 1200	230	12	2	1	6	0.1	1k

#### 2SA965 (TR0263)

#### Absolute Maximum Ratings (Ta = 25°C) ELECTRICAL CHARACTERISTICS (Ta = 25°C)

SYMBOL	RATING	UNIT
V <sub>CBO</sub>	-120	V
v <sub>ceo</sub>	-120	V
V <sub>EBO</sub>	-5	V
<sup>I</sup> c	-800	nn.A
IE	800	mA
P <sub>C</sub>	900	mW
Tj	150	°C
Tstg.	-55-150	°C

		100	221 . 7 4	the second	
SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	V <sub>OB</sub> =-120V, I <sub>E</sub> =0	- 1	- 1	-100	nA
I <sub>EBO</sub>	V <sub>EB</sub> =-5V, I <sub>C</sub> =0	-	-	-100	Acr
V(BR)CEO	$I_{C}^{=-10\text{mA}}$ , $I_{B}^{=0}$	-120	-	-	V
V(BR)EBO	$I_{E}$ =-lmA, $I_{C}$ =0	-5	-	-	V
h <sub>FE</sub>	V <sub>CE</sub> =-5V, I <sub>C</sub> =-100mA	80	-	240	
V CE(sat)	I <sub>C</sub> =-500mA, I <sub>B</sub> =-50mA	-	-	-1.0	V
V <sub>BE</sub>	V <sub>CE</sub> =-5V, I <sub>C</sub> =-500mA	-	-	-1.0	V
f <sub>T</sub>	$V_{CE}$ =-5V, $I_{E}$ =-100mA	-	120	-	MHz
Cob	$V_{CB} = -10V$ , $I_{E} = 0$ , $f = 1MHz$	-	-	30	pF

#### 2SC2235 (TR0264)

RATING	UNIT
120	V
120	V
5	V
800	mA
800	mA.
900	mW
150	°C
<b>-55 - 15</b> 0	°C
	120 120 5 800 800 900 150

#### Absolute Maximum Ratings (Ta = 25°C) ELECTRICAL CHARACTERISTICS (Ta = 25°C)

SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT
v <sub>CBO</sub>	V <sub>CB</sub> =120V, I <sub>E</sub> =0	-	-	100	n.A
I <sub>EBO</sub>	$v_{EB}^{=5}v$ , $I_{C}^{=0}$	-	-	100	nA.
V (BR) CEO	I <sub>C</sub> =10mA, I <sub>B</sub> =0	120	-	-	V
V <sub>(BR)EBO</sub>	I <sub>E</sub> =1mA, I <sub>C</sub> =0	5	-	-	v
h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =100mA	80	-	240	
V <sub>CE(sat)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> =50mA	-	- :	1.0	v
V <sub>BE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =500mA	-	-	1.0	v
f <sub>T</sub>	V <sub>CE</sub> =5V, I <sub>E</sub> =100mA	-	120	-	MHz
C <sub>OP</sub>	$V_{CB}$ =10V, $I_E$ =0, f=1MHz	-	-	<b>3</b> 0	pF

#### 2SC2229 (TR0236)

SYMBOL	RATINGS	UNIT
v <sub>CBO</sub>	200	V
V <sub>CEO</sub>	150	v
V <sub>EBO</sub>	5	٧
I <sub>C</sub>	50	m.A
I <sub>E</sub>	-50	m.A
P <sub>C</sub>	800	mW
<sup>T</sup> j	150	*C
Tstg	-55 <b>- 1</b> 50	*c

#### Absolute Maximum Ratings (Ta=25°C) ELECTRICAL CHARACTERISTICS (Ta = 25°C)

SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT
СВО	$V_{CB}^{=200V}, I_{E}^{=0}$	-	-	0.1	μA
I <sub>EBO</sub>	v <sub>EB</sub> =5v, 1 <sub>C</sub> =0	-	-	0.1	μA
h <sub>FE</sub>	V <sub>CE</sub> =6V, I <sub>C</sub> =10mA	70	-	240	
V <sub>CE(sat)</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =1mA	-	-	0.5	V
V <sub>BE(sat)</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =1mA	-	-	1	V
f <sub>T</sub>	V <sub>CE</sub> =30V, I <sub>E</sub> =-10mA	-	120	<b>-</b>	MHz
Cop	V <sub>CE</sub> =10V, I <sub>E</sub> =0, f=1MHz	-	3.5	5	pF

## Silicon Rectifier Diode S3V40(TD0106)

I <sub>0</sub> (A)	V <sub>RM</sub> (V)	I <sub>FSM</sub> (A)	P <sub>RSM</sub> (W)	T, (°C)		$I_R$ ( $\mu$ A) MAX. at $V_{RM}$	V (V) MIN.
3.5	400	120		+150	1.05	5	

#### Zener Diode WZ-192(TD0065)

ZENER VOLTAGE VZ(V) OPERATING RESISTANCE Rd(\O)		TING RESISTANCE Rd(\Omega)	REVER	SE CURRENT IR (μA)		
MIN.	MAX.	@IZ(mA)	MAX.	@IZ(mA)	MAX.	@VR(V)
18.4	20.1	5	20	5	1	16

## Silicon Rectifier Diodes

1N4002/1N4003(TD0002/TD0003)	1N4002	1N4003	UNIT
Maximum Peak Reverse Voltage	100	200	v
Maximum Input Voltage(RMS)	70	140	v
Maximum DC Reverse Voltage	100	200	v
Maximum Output Current(ave.)	1.0	)	A
Surge Current	30	30	
Maximum Forward Voltage Drop	1.1		V
Maximum Full-Load Reverse Current	30		μА
DC Reverse Current	5.0(25°C),50.0(75°C)		μА
Reverse Recovery Time	20		μS
Capacitance	15		pF
Thermal Resistance	50		°C/W
Operating Temperature	-65 ~	+175	°C
Storage Temperature	-65 ∼ +175		°C

#### L-2 SPECIFICATIONS

Power Output:		ms, both channels driven)	
Total Harmonic Distortion:	no more than 0. (8 ohms, 33W/c	.03% h, both ch. driven)	
Rated I.M.:	no more than 0 (8 ohms, 33W/c	.06% ch, 60Hz : 7kHz = 4 : 1)	
Frequency Response:	15Hz ~ 60kHz		
Input Sensitivity & Input Impedance:	PHONO TUNER AUX MONITOR-1 MONITOR-2	2.5mV 50k ohms 145mV 50k ohms	
Signal-to-Noise Ratio: (input short-circuited)	PHONO	better than 84dB (IHF-A weighted, 10mV)	
	TUNER	better than 90dB (IHF-A weighted)	
	AUX	better than 90dB (IHF-A weighted)	
	MONITOR-1	better than 90dB (IHF-A weighted)	
	MONITOR-2	better than 90dB (IHF-A weighted)	
Residual Noise:	no more than		
Tone Control:	LUX NF type	(100Hz ±11dB, 10kHz ±10dB)	
Filter:	High Cut Subsonic	7kHz (—6dB/oct.) 25Hz (—6dB/oct.)	
Channel Separation:	PHONO AUX	better than 60dB better than 70dB	
Additional Features:	Mode Selector (E-type, S-typ		
Dimensions:	438(W) x 289 (17-1/4" x 11 (including Leg	(D) x 105(H) -3/8" x 4-1/8") ps, Rear Protrusions and Knobs)	
Weight:	Net Gross	7.5kgs (16.5 lbs.) 9.0kgs (19.8 lbs.)	

Specifications and appearance design subject to change without notice.

